# **Slotted Optical Switch**

### **OPB804**

# **Electronics**

#### Features:

- Non-contact switch
- PCB mount
- Wide aperture
- Opaque body to minimize sensitivity to ambient light



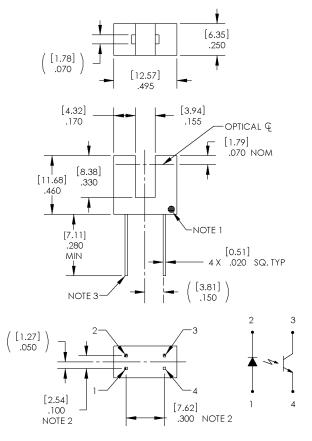
#### **Description:**

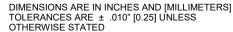
OPB804 is a non-contact optical switch with a NPN silicon phototransistor and infrared Light Emitting Diode (LED) which are mounted on opposite sides of a 0.155" (3.94 mm) wide slot.

The device body is a single molded piece opaque plastic that reduces ambient light interference. A wide open aperture makes it versatile for general applications. LED emissions are near-infrared (850 – 940nm).

#### **Applications:**

- Non-contact object sensing
- Assembly line automation
- Machine automation
- · Equipment security
- Machine safety







# **Slotted Optical Switch**

## **OPB804**



## **Electrical Specifications**

#### **Absolute Maximum Ratings** (T<sub>A</sub> = 25° C unless otherwise noted)

Storage Temperature Range	-40°C to +100° C
Operating Temperature Range	-40°C to +85° C
Lead Soldering Temperature	260° C <sup>(5</sup>
Input Diode	
Input Diode Power Dissipation	75 mW <sup>(7</sup>
Input Diode Forward D.C. Current, T <sub>A</sub> = 25°C	50 mA <sup>(7</sup>
Input Diode Peak Forward Pulse Current, $T_A = 25$ °C (1 $\mu$ s pulse width, 300pps)	1/
Phototransistor	
Power Dissipation	100 mW <sup>(7</sup>
Collector - Emitter Voltage	30
Emitter - Collector Voltage	5.0

#### **Electrical Characteristics** ( $T_A = 25$ °C)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS	
Input Diode (see OP140 or OP240 for additional information)							
V <sub>F</sub>	Forward Voltage	-	1.25	1.70	V	I <sub>F</sub> = 20 mA	
I <sub>R</sub>	Reverse Current	-	-	-	-	Not designed for reverse operation	

#### Output Phototransistor (see OP550 for additional information)

V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	30	ı	ı	٧	$I_C = 1 \text{ mA}, E_E = 0 \text{ mw/cm}^2$
V <sub>(BR)ECO</sub>	Emitter-Collector Breakdown Voltage	5.0	1	1	٧	$I_E = 100 \mu A, E_E = 0 \text{ mw/cm}^2$
I <sub>CEO</sub>	Collector Dark Current	-	-	100	nA	$V_{CE} = 10 \text{ V}, I_F = 0, E_E = 0 \text{ mw/cm}^2$

#### Coupled

V <sub>CE(SAT)</sub>	Collector-Emitter Saturation Voltage	-	-	0.40	٧	$I_C = 250 \mu A$ , $I_F = 20 \text{ mA}$
I <sub>C(ON)</sub>	On-State Collector Current	0.5	5	-	mA	$V_{CE} = 10 \text{ V}, I_F = 20 \text{ mA}$

#### Notes:

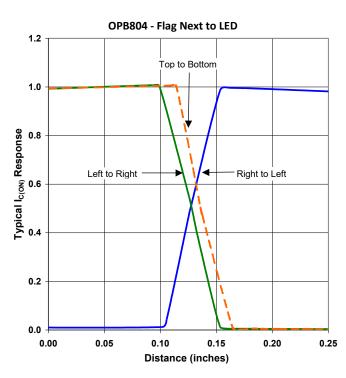
- (1) Dot indicates # 3 collector lead side.
- (2) Feature controlled at body.
- (3) Cathode lead may be shorter.
- (4) RMA flux recommended. Highly activated water soluble fluxes may attack plastic. Recommend trial to verify application.
- (5) Maximum lead soldering temperature .060" [1.6mm] from case for 5 seconds with soldering iron.
- (6) Plastic is soluble in chlorinated hydrocarbons and ketones. Methanol or isopropanol are recommended as cleaning agents.
- (7) Derate linearly 1.67 mW/°C above 25° C.
- (8) All parameters tested using pulse techniques.
- 9) Do not connect input diode directly to a voltage source without an external current limiting resistor.
- (10) Do not apply reverse voltage to LED. LED will be a 0V in reverse voltage and draw current as if a short.

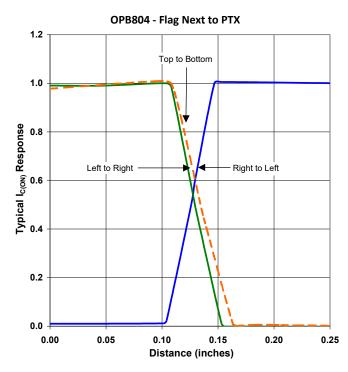
# **Slotted Optical Switch**

## **OPB804**

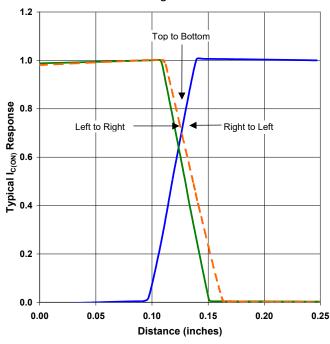


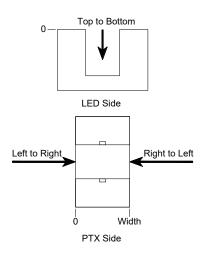
## **Performance**





#### OPB804 - Flag in Middle of Slott





# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

TT Electronics: